

-100mA / -50V Digital transistors (with built-in resistors)

DTA124TM / DTA124TE / DTA124TUA / DTA124TKA

● Applications

Inverter, Interface, Driver

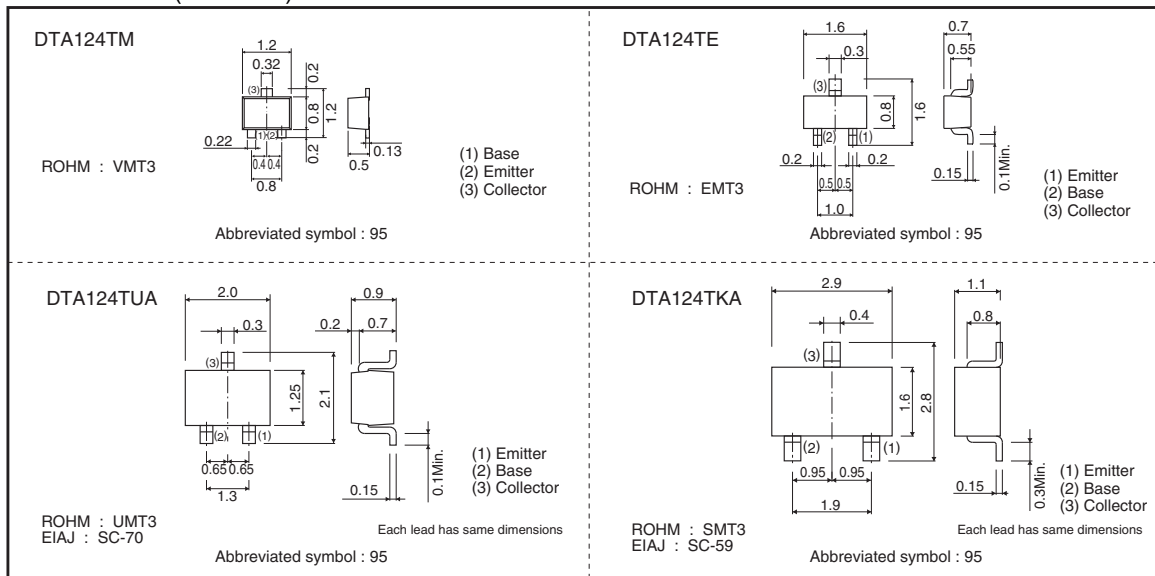
● Features

- 1) Built-in circuit enables the configuration of an inverter circuit without connecting external input resistors. (see equivalent circuit).
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on / off conditions need to be set for operation, making the device design easy.

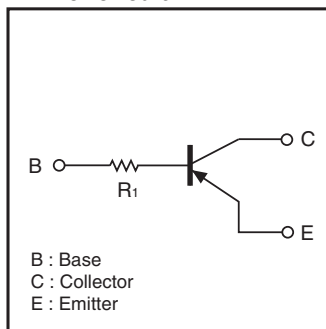
● Structure

PNP epitaxial planar silicon transistor (Resistor built-in type)

● Dimensions (Unit : mm)



● Inner circuit



$R_1 = 22k\Omega$

● Packaging specifications

Part No.	Package	VMT3	EMT3	UMT3	SMT3
	Package type	Taping	Taping	Taping	Taping
	Code	T2L	TL	T106	T146
	Basic ordering unit (pieces)	8000	3000	3000	3000
DTA124TM		○	-	-	-
DTA124TE		-	○	-	-
DTA124TUA		-	-	○	-
DTA124TKA		-	-	-	○

● Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits				Unit
		DTA124TM	DTA124TE	DTA124TUA	DTA124TKA	
Collector-base voltage	V _{CB0}	-50				V
Collector-emitter voltage	V _{CE0}	-50				V
Emitter-base voltage	V _{EBO}	-5				V
Collector current	I _c	-100				mA
Collector power dissipation	P _c	150		200		mW
Junction temperature	T _j	150				°C
Storage temperature	T _{stg}	-55 to +150				°C

● Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV _{CB0}	-50	-	-	V	I _c =-50μA
Collector-emitter breakdown voltage	BV _{CE0}	-50	-	-	V	I _c =-1mA
Emitter-base breakdown voltage	BV _{EBO}	-5	-	-	V	I _E =-50μA
Collector cutoff current	I _{cBO}	-	-	-0.5	μA	V _{CB} =-50V
Emitter cutoff current	I _{EBO}	-	-	-0.5	μA	V _{EB} =-4V
Collector-emitter saturation voltage	V _{CE(sat)}	-	-	-0.3	V	I _c /I _B =-5mA/-0.5mA
DC current transfer ratio	h _{FE}	100	250	600	-	V _{CE} =-5V, I _c =-1mA
Input resistance	R _i	15.4	22	28.6	kΩ	-
Transition frequency	f _t *	-	250	-	MHz	V _{CE} =-10V, I _E =5mA, f=100MHz

* Characteristics of built-in transistor

● Electrical characteristic curves

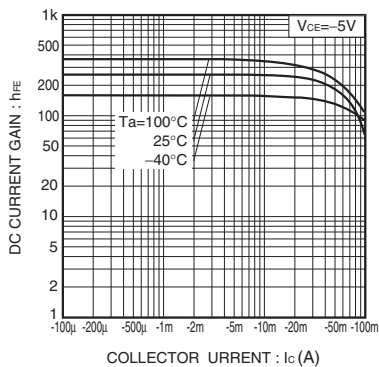


Fig.1 DC current gain vs. collector current

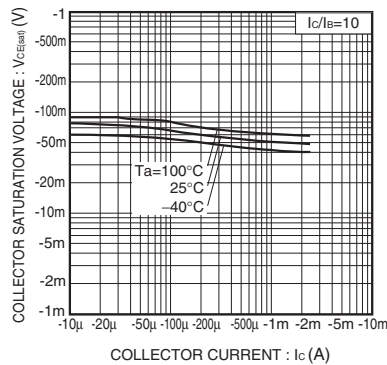


Fig.2 Collector-emitter saturation voltage vs. collector current

Notes

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